

Continental Device India Limited

An IS/ISO 9002 and IECQ Certified Manufacturer

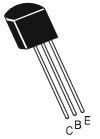


SILICON PLANAR EPITAXIAL TRANSISTORS

BC 413, B, C BC 414, B, C

TO-92

Plastic Package



Low Noise Transistors

ABSOLUTE MAXIMUM RATINGS (Ta=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	BC 413	BC414	UNITS	
Collector Emitter Voltage	V_{CEO}	30	45	V	
Collector Base Voltage	V_{CBO}	45	50	V	
Emitter Base Voltage	V_{EBO}	5.0		V	
Collector Current Continuous	I _C	100		mA	
Total Device Dissipation@ Ta=25°C	P_D	350		mW	
Derate Above 25°C		2.	8	mW/ °C	
Total Device Dissipation@ Tc=25°C	P_{D}	1.	1.0		
Derate Above 25°C		8.	0	mW/ °C	
Operating And Storage Junction Temperature Range	T_{j},T_{stg}	-55 to +150		°C	
THERMAL RESISTANCE					
Junction to ambient	$R_{th(j-a)}$	35	57	°C/W	
Junction to case	$R_{th(j-c)}$	12	25	°C/W	

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ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)								
DESCRIPTION	SYMBO	LTEST CONDITION	MIN	TYP	MAX	UNITS		
Collector Emitter Breakdown Voltage	BV_CEO	$I_C=10mA,I_B=0$						
BC413	}		30			V		
BC414	i		45			V		
Collector Base Breakdown Voltage	BV_CBO	$I_C=10uA$, $I_E=0$						
BC413	}		45			V		
BC414	•		50			V		
Emitter Base Breakdown Voltage	BV_{EBO}	$I_E=10uA, I_C=0$	5			V		
Collector-Cut off Current	I_{CBO}	$V_{CB} = 30V$, $I_E = 0$			15	nA		
		$V_{CB} = 30V, I_{E} = 0$			5	μΑ		
		Ta = +125 ^o C						
Emitter cut off Current	I_{EBO}	$V_{EB} = 4V$, $I_C = 0$			15	nA		
DC Current Gain	h_{FE}							
BC413B, BC414B		$I_C=10uA, V_{CE}=5V$	100					
BC413C, BC414C	;		100					
BC413B, BC414B	1	$I_C=2mA, V_{CE}=5V$	180		460			
BC413C, BC414C	;		380		800			
BC413, BC414			180		800			
	., .					.,		
Collector Emitter Saturation Voltage	V _{CE(sat})	$I_C=10\text{mA}, I_B=0.5\text{mA}$			0.25	V		
		I _C =10mA,I _B =see note	e 1		0.60	V		
	V _{CE(sat) 2}	$I_C=100$ mA, $I_B=5$ mA			0.60	V		
Base Emitter Saturation Voltage	()	$I_C=100\text{mA}, I_B=5\text{mA}$		1.10		V		
Base Emitter On Voltage	$V_{BE(on)}$	$I_C=10uA, V_{CE}=5V$		0.52		V		
		$I_C=100uA, V_{CE}=5V$		0.55		V		
		$I_C=2mA, V_{CE}=5V$	0.55		0.75	V		

ELECTRICAL CHARACTERISTICS (Ta=25°C unless specified otherwise)

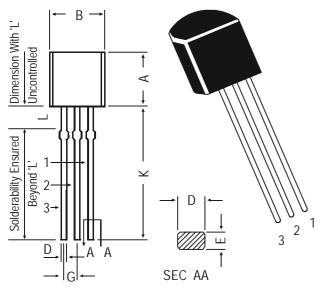
DESCRIPTION	SYMBO	L TEST CONDITION	MIN	TYP	MAX	UNITS
DYNAMIC CHARACTERISTICS						
Transition Frequency	f⊤	$I_C=10$ mA, $V_{CF}=5$ V		250		MHz
	-1	f=100MHz				
Collector Base Capacitance	C_cbo	$V_{CE} = 10V, I_{E} = 0,$		2.5		pF
		f =1MHz				
Noise Figure	NF	$I_C=0.2$ mA, $V_{CE}=5$ V			2.5	dB
		$R_s=2K\Omega$ f=30Hz-15K	Ήz		.	-

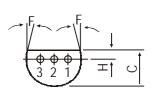
Note 1 : I_B is value for which I_C =11mA@ V_{CE} =1V

Note 2 : Pulse test = 300μ s, Duty Cycle 2%.

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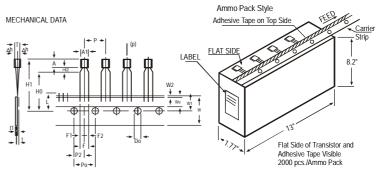
PIN CONFIGURATION

- 1. EMITTER
- BASE 2.
- COLLECTOR

DIM	MIN.	MAX.					
Α	4.32	5.33					
В	4.45	5.20					
С	3.18	4.19					
D	0.41	0.55					
Е	0.35	0.50					
F	5 DEG						
G	1.14	1.40					
Н	1.14	1.53					
K	12.70	_					
L	1.982	2.082					

All diminsions in mm.

TO-92 Transistors on Tape and Ammo Pack



All dimensions in mm unless specified otherwise

ITEM		SPECIFICATION				REMARKS	
ITEM	SYMBOL	MIN. NOM. MAX. TOL.					
BODY WIDTH	A1	4.0		4.8			
BODY HEIGHT	A	4.8		5.2			
BODY THICKNESS	T P	3.9	10.7	4.2	. 1		
PITCH OF COMPONENT FEED HOLE PITCH	Po		12.7 12.7		±1 +0.3	CUMULATIVE PITCH	
FFED HOLE CENTRE TO	PU		12.7		±0.3	ERROR 1.0 mm/20	
COMPONENT CENTRE	P2		6.35		±0.4	TO BE MEASURED AT BOTTOM OF CLINCH	
DISTANCE BETWEEN OUTER					+0.6		
LEADS	F		5.08		-0.2		
COMPONENT ALIGNMENT	Δh		0	1	0.5	AT TOP OF BODY	
TAPE WIDTH HOLD-DOWN TAPE WIDTH	W Wo		18 6		±0.5 ±0.2		
HOLE POSITION	W1		9		±0.2 +0.7		
HOLE POSITION	VVI		,		-0.5		
HOLD-DOWN TAPE POSITION	W2		0.5		±0.2		
LEAD WIRE CLINCH HEIGHT	Ho		16		±0.5		
COMPONENT HEIGHT	H1			23.25			
LENGTH OF SNIPPED LEADS	L			11.0			
FEED HOLE DIAMETER TOTAL TAPE THICKNESS	Do t		4	1.2	±0.2	t1 0.3 - 0.6	
LEAD - TO - LEAD DISTANCEF1.	F2		2.54	1.2	+0.4	11 0.3 - 0.0	
			2.54		-0.1		
CLINCH HEIGHT	H2	ا		3			
PULL - OUT FORCE	(P)	6N					

NOTES

- 1. MAXIMUM ALIGNMENT DEVIATION BETWEEN LEADS NOT TO BE GREATER THAN 0.2 mm.
 2. MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCEED 1 mm IN 20 PITCHES.
- 3. HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO
- 3. HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO EXPOSURE OF ADHESIVE.
 4. NO MORE THAN 3 CONSECUTIVE MISSING COMPONENTS ARE PERMITTED.
 5. A TAPE TRAILER, HAVING AT LEAST THREE FEED HOLES ARE REQUIRED AFTER THE LAST COMPONENT.
 6. SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX				
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt		
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs		
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs		

Notes

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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